

Features

- $BV_{CEO} > 80V$
- $I_C = 1A$ High Continuous Collector Current
- $I_{CM} = 2A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < 500mV @ 0.5A$
- Low Profile 0.62mm High Package for Thin Applications
- Sidewall Tin Plating for Wettable Flanks in AOI
- 4mm² Footprint, 50% Smaller Than SOT23
- Complementary PNP Type: BC53-16PAWQ
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The BC56-16PAWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

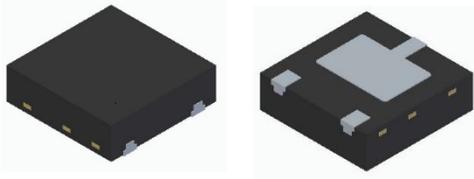
Mechanical Data

- Package: W-DFN2020-3/SWP (Type A)
- Nominal Package Height: 0.6mm
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Max Soldering Temperature +260°C for 30 secs as per JEDEC J-STD-020
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin, Solderable per MIL-STD-202, Method 208 ②③
- Weight: 0.01 grams (Approximate)

Applications

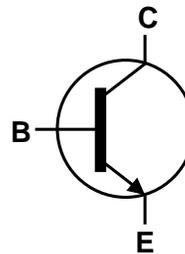
- Medium power switching or amplification applications
- AF driver and output stages

W-DFN2020-3/SWP (Type A)

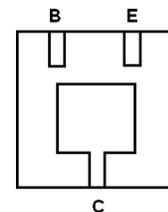


Top View

Bottom View



Device Symbol



Bottom View Pin-Out

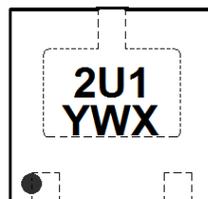
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Quantity	Carrier
BC56-16PAWQ-7	W-DFN2020-3/SWP (Type A)	2U1	7	8	3,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

W-DFN2020-3/SWP



- 2U1 = Product Type Marking Code
- Y = Year: 0~9
- W = Week: A~Z: 1~26 Week;
a~z; 27~52 Week; z Represents 52 and 53 Week
- X = A~Z: Internal Code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	100	V
Collector-Emitter Voltage	V _{CEO}	80	
Emitter-Base Voltage	V _{EBO}	7	
Continuous Collector Current	I _C	1	A
Peak Pulse Collector Current	I _{CM}	2	
Base Current	I _B	300	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	500	mW
Linear Derating Factor		(Note 5)	6
Thermal Resistance, Junction to Ambient	R _{θJA}	250	°C/W
Thermal Resistance, Junction to Case	R _{θJC}	40	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes: 5. For a device mounted with the collector tab on FR-4 substrate PC board ,2oz copper, with minimum recommended pad layout; device is measured under still air conditions whilst operating in a steady-state.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

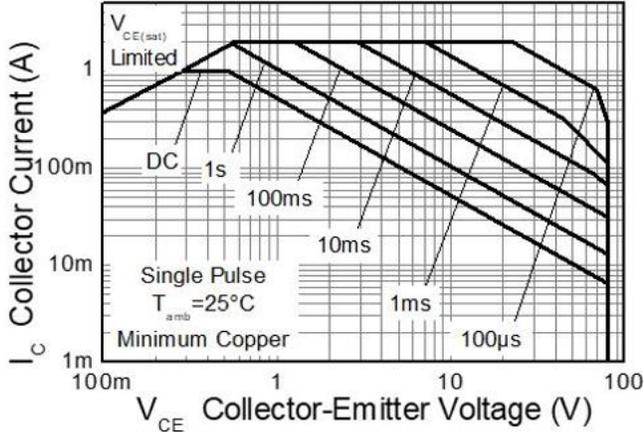


Fig.1 Safe Operating Area

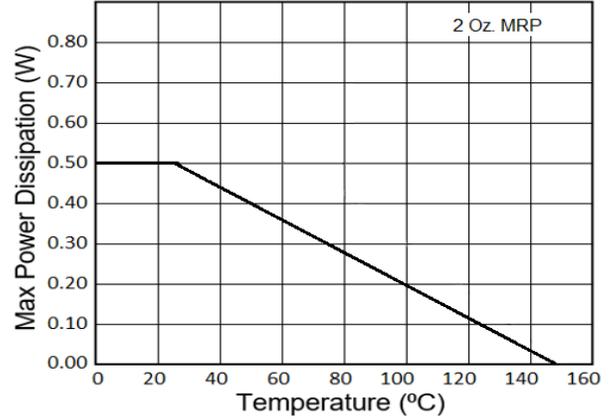


Fig.2 Derating Curve

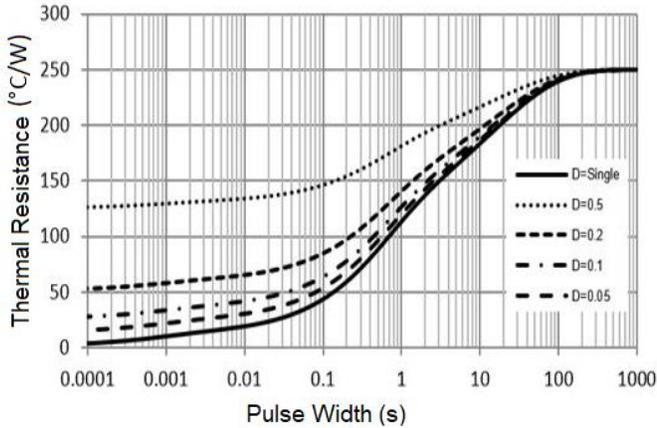


Fig.3 Transient Thermal Resistance

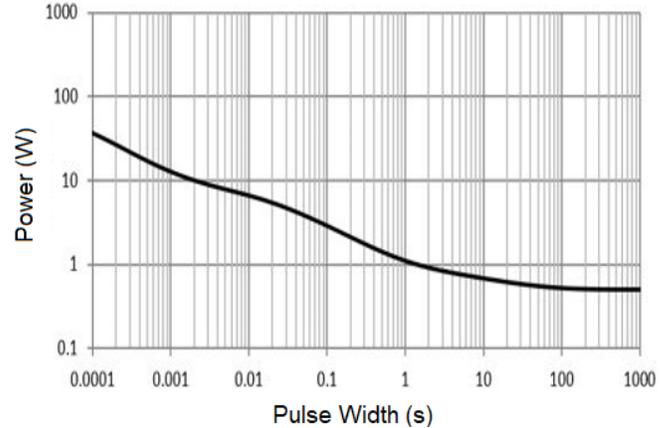


Fig.4 Power vs Pulse Width

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	100	—	—	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV_{CEO}	80	—	—	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.6	—	V	$I_E = 100\mu A$
Collector Cut-Off Current	I_{CBO}	—	1 0.3	100 10	nA μA	$V_{CB} = 30V$ $V_{CB} = 30V, T_A = +150^\circ C$
Emitter Cut-Off Current	I_{EBO}	—	3	100	nA	$V_{EB} = 6V$
DC Current Gain (Note 7)	h_{FE}	63 100 40	156 152 65	250	—	$I_C = 5mA, V_{CE} = 2V$ $I_C = 150mA, V_{CE} = 2V$ $I_C = 500mA, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 7)	$V_{CE(sat)}$	—	122	500	mV	$I_C = 500mA, I_B = 50mA$
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	—	0.83	1	V	$I_C = 500mA, V_{CE} = 2V$
Transition Frequency	f_T	100	150	—	MHz	$I_C = 50mA, V_{CE} = 10V$ $f = 100MHz$
Output Capacitance	C_{obo}	—	4	15	pF	$V_{CB} = 10V, f = 1MHz$
Switching Times	t_{delay}	—	8	—	ns	$I_C = 1A, V_{CC} = 10V,$ $I_{B1} = -I_{B2} = 100mA$
	t_{rise}	—	305	—	ns	
	$t_{storage}$	—	160	—	ns	
	t_{fall}	—	115	—	ns	

Note: 7. Measured under pulsed conditions. Pulse width $\leq 300\mu s$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics

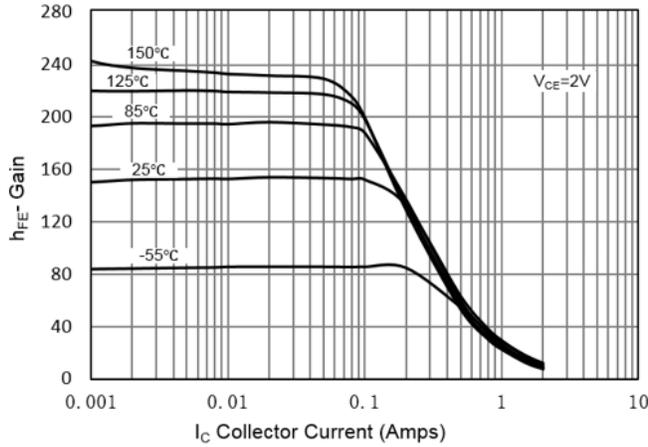


Fig.5 h_{FE} vs I_C

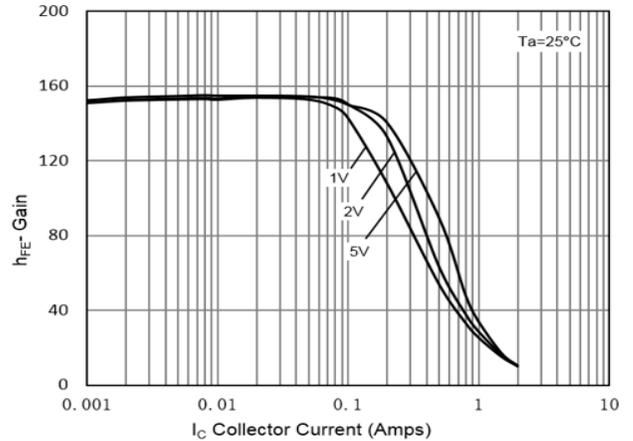


Fig.6 h_{FE} vs I_C

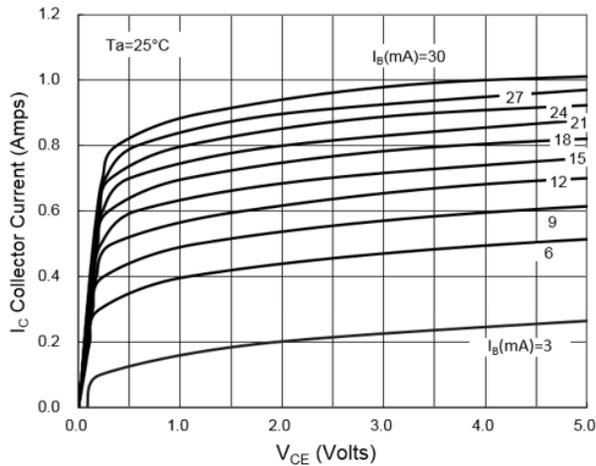


Fig.7 V_{CE} vs I_C

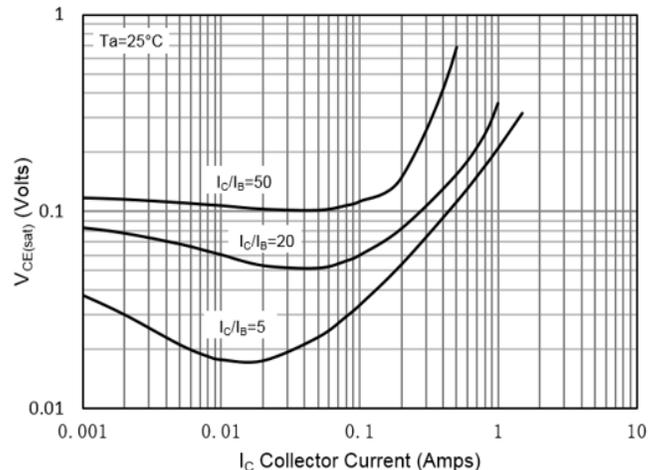


Fig.8 $V_{CE(sat)}$ vs I_C

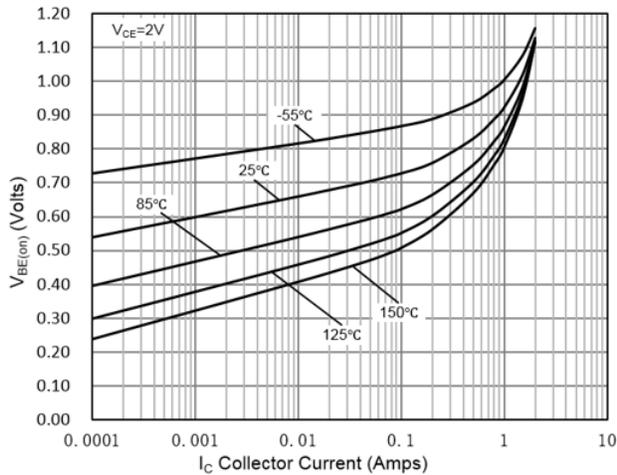


Fig.9 $V_{BE(on)}$ vs I_C

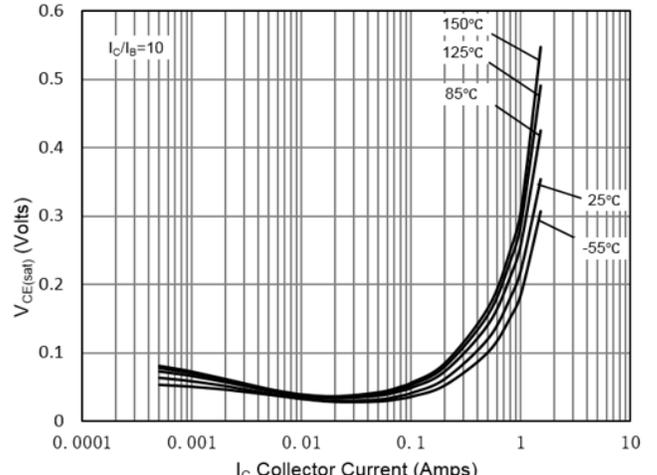
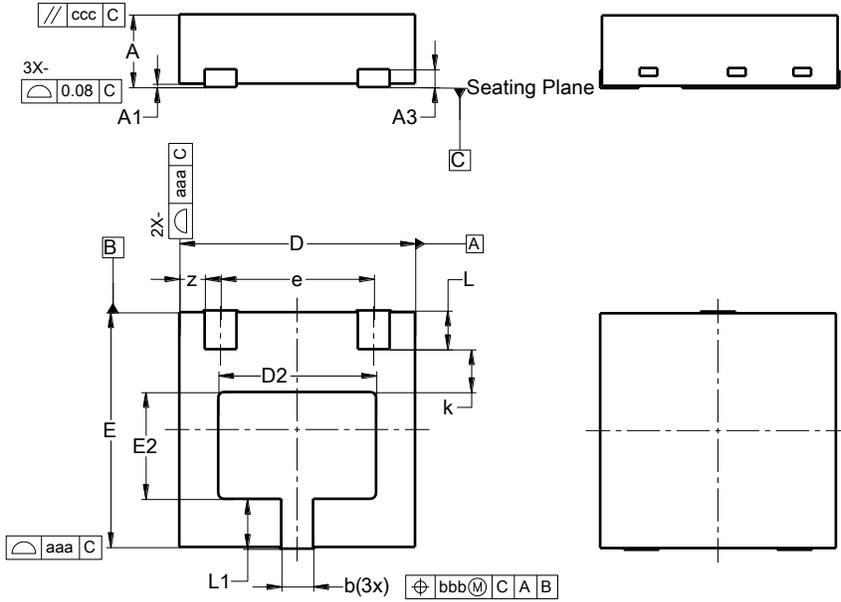


Fig.10 $V_{CE(sat)}$ vs I_C

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

W-DFN2020-3/SWP (Type A)

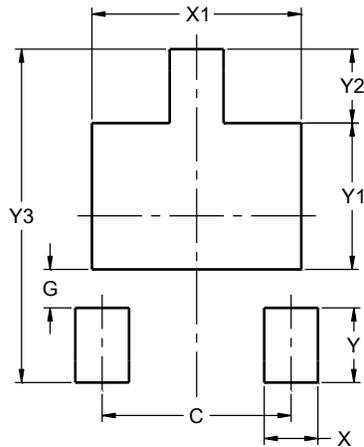


W-DFN2020-3 /SWP (Type A)			
Dim	Min	Max	Typ
A	0.57	0.67	0.62
A1	0.00	0.05	0.03
A3	0.100	--	0.152
b	0.22	0.32	0.27
D	1.95	2.05	2.00
D2	1.24	1.44	1.34
E	1.95	2.05	2.00
E2	0.81	1.01	0.91
e	--	--	1.30
k	--	--	0.365
L	0.28	0.38	0.33
L1	0.375	0.475	0.425
z	--	--	0.215
aaa	0.25		
bbb	0.10		
ccc	0.10		
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

W-DFN2020-3/SWP (Type A)



Dimensions	Value (in mm)
C	1.300
G	0.265
X	0.370
X1	1.440
Y	0.515
Y1	1.010
Y2	0.510
Y3	2.300

IMPORTANT NOTICE

1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
5. Diodes' products are provided subject to Diodes' Standard Terms and Conditions of Sale (<https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/>) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
9. This Notice may be periodically updated with the most recent version available at <https://www.diodes.com/about/company/terms-and-conditions/important-notice>

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries.
All other trademarks are the property of their respective owners.
© 2023 Diodes Incorporated. All Rights Reserved.

www.diodes.com